

Ref #	Hits	Search Query	DBs	Default Operator	Plurals	Time Stamp
S43	496	365/185.01.ccls.	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/17 15:48
S44	1468	(control adj3 gate) with (float\$3 adj3 gate) with (insulat\$3 dielectric barrier) with thick\$4	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/17 17:26
S45	53	S43 and S44	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/17 15:50
S46	389	S44 same (angstrom micron nanometer nm\$1)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/17 16:15
S47	19	S43 and S46	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/17 15:51
S48	365	S44 same (angstrom micron nanometer nm\$1)	US-PGPUB; USPAT	OR	ON	2005/09/17 16:09
S49	257	S44 same (angstrom micron nanometer nm\$1)	USPAT	OR	ON	2005/09/17 16:10
S50	108	S44 same (angstrom micron nanometer nm\$1)	US-PGPUB	OR	ON	2005/09/17 16:10
S51	66	S44 same (angstrom micron nanometer nm\$1) and ("20" adj (ang angstrom)) or ("2" adj nm\$1))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/17 17:08
S52	3	S51 and ((tunnel near3 insulat\$3) with (transition\$2 near3 metal near3 oxide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/17 17:26

S53	3	S51 and ((tunnel near3 insulat\$3) with (Perovskite near3 oxide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/17 17:26
S54	3	S52 and S53	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/17 17:23
S55	3	S44 and ((tunnel near3 insulat\$3) with (transition\$2 near3 metal near3 oxide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/17 17:25
S56	3	S44 and ((tunnel near3 insulat\$3) with (Perovskite near3 oxide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/17 17:24
S57	3	S44 and ((tunnel with insulat\$3) with (Perovskite near3 oxide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/17 17:25
S58	4	S44 and ((tunnel with insulat\$3) with (transition\$2 near3 metal near3 oxide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/17 17:25
S59	3800	(control adj3 gate) same (float\$3 adj3 gate) same (tunnel with (insulat\$3 dielectric barrier))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/17 17:28
S60	22	S59 and ((tunnel near3 insulat\$3) with (transition\$2 near3 metal near3 oxide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/17 17:32

S61	21	S59 and ((tunnel near3 insulat\$3) with (Perovskite near3 oxide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/17 17:29
S62	21	S60 and S61	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/17 17:27
S63	13164	(control adj3 gate) same (float\$3 adj3 gate) same (insulat\$3 dielectric barrier)	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/17 17:28
S64	22	S63 and ((tunnel near3 insulat\$3) with (transition\$2 near3 metal near3 oxide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/17 17:29
S65	22	S63 and ((tunnel near3 insulat\$3) with (transition\$2 near3 metal near3 oxide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/17 17:29
S66	23	S63 and (tunnel with (transition\$2 near3 metal near3 oxide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/17 17:29
S67	21	S63 and (tunnel with (Perovskite near3 oxide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/17 17:30
S68	23	S59 and ((tunnel near3 insulat\$3) with (Aluminum near3 oxide))	US-PGPUB; USPAT; USOCR; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/17 17:32

S69	22	((polysilicon near3 floating near3 gate) and (polysilicon near3 control near3 gate) and source and drain and channel and substrate and (tunnel adj3 barrier)).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/23 13:52
S70	3	((polysilicon near3 floating near3 gate) and (polysilicon near3 control near3 gate) and source and drain and channel and substrate and (tunnel adj3 barrier) and (thickness near3 (ev or angstrom))).clm.	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/23 13:53
S71	5037	(257/315)".ccls" (257/316)".ccls" (257/317)".ccls"	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/23 13:54
S72	190	((257/315)".ccls" (257/316)".ccls" (257/317)".ccls") and pillar	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/23 13:55
S73	190	((257/315)".ccls" (257/316)".ccls" (257/317)".ccls") and pillar	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/23 13:55
S74	164	(((257/315)".ccls" (257/316)".ccls" (257/317)".ccls") and pillar) and drain and source and substrate	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/23 13:55
S75	99	(((257/315)".ccls" (257/316)".ccls" (257/317)".ccls") and pillar) and drain and source and substrate) and (floating adj2 gate)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/23 13:55
S76	12	((((257/315)".ccls" (257/316)".ccls" (257/317)".ccls") and pillar) and drain and source and substrate) and (floating adj2 gate)) and (tunnel adj2 barrier)	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/23 13:55
S77	8	((((((257/315)".ccls" (257/316)".ccls" (257/317)".ccls") and pillar) and drain and source and substrate) and (floating adj2 gate)) and (tunnel adj2 barrier)) and ev	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/23 13:55

S78	10	((((257/315)".ccls" (257/316)".ccls" (257/317)".ccls") and pillar) and drain and source and substrate) and (floating adj2 gate)) and eV	US-PGPUB; USPAT; EPO; JPO; DERWENT; IBM_TDB	OR	ON	2005/09/23 13:56
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